

Notice of References CitedApplication/Control No.
09/759,312Applicant(s)/Patent Under Reexam
Ueta et alExaminer
Savitri MulpuriArt Unit
2812

Page 1 of 1

U.S. PATENT DOCUMENTS

	Document Number Country Code-Number-Kind Code	Date MM-YYYY ¹	Name	Classification ²	
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FOREIGN PATENT DOCUMENTS

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NON-PATENT DOCUMENTS

	Include, as applicable: Author, Title, Date, Publisher, Edition or Volume, Pertinent Pages
U	Zauner et al , " Homo-epitaxial growth on misoriented GaN substrates by MOCVD" Mat. Res.Soc.Symp. Vol. 595 2000 Materials Research society
V	
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X	

¹ A copy of this reference is not being furnished with this Office action. See MPEP § 707.05(a).¹ Dates in MM-YYYY format are publication dates.² Classifications may be U.S. or foreign.